
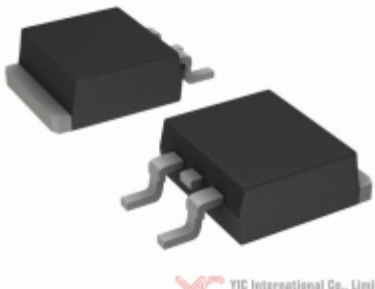
	<h2 style="color: #E67E22;">FQB4N50TM</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FQB4N50TM</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 500V 3.4A D2PAK</p> <p><b>Datenblätter:</b>  <a href="#">FQB4N50TM.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 32363 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQB4N50TM</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 500V 3.4A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	32363 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 70W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	3.4A (Tc)
Rds On (Max) @ Id, Vgs	2.7 Ohm @ 1.7A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	13nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	460pF @ 25V
Verpackung	Tape & Reel (TR)









































FQB4N50TM ist neu im Original, Suche FQB4N50TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB4N50TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB4N50TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>FQB4N80</b> FAIRCHILD FQB4N80 FAIRCHILD	 <b>FQB4N20TM</b> VB FQB4N20TM VB	 <b>FQB4N60</b> Fairchild/ON Semiconductor FQB4N60 FAIRCHILD	 <b>FQB4N25TM</b> Fairchild/ON Semiconductor MOSFET N-CH 250V 3.6A D2PAK
 <b>FQB4N60C</b> FAIRCHI FQB4N60C FAIRCHI	 <b>FQB4N70</b> Fairchild/ON Semiconductor FQB4N70 FAIRCHILD	 <b>FQB4N50</b> VB FQB4N50 VB	 <b>FQB4N50TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 3.4A D2PAK

### heiße Teile

Mehr

 FQB3N60C	 FQB3N80TM	 FQB3N80TM	 FQB3N90TM	 FQB3N90TM
 FQB3P20TM	 FQB3P20TM	 FQB3P50TM	 FQB3P50TM	 FQB44N10
 FQB44N10TM	 FQB44N10TM	 FQB46N15	 FQB46N15TM	 FQB47P06
 FQB47P06TM	 FQB4N20L	 FQB4N20LTM	 FQB4N20LTM	 FQB4N20TM
 FQB4N20TM	 FQB4N25TM	 FQB4N25TM	 FQB4N20TM	 FQB4N50TM
 FQB4N60C	 FQB4N80TM	 FQB4N80TM	 FQB4N90TM	 FQB4N90TM
 FQB4P25TM	 FQB4P25TM	 FQB50N03	 FQB50N06	 FQB50N06C
 FQB50N06L	 FQB50N06LTM	 FQB50N06LTM	 FQB50N06M	 FQB50N06TM
 FQB50N06TM	 FQB50N06TM-NL	 FQB55N06TM	 FQB55N06TM	 FQB55N10
 FQB55N10TM	 FQB55N10TM	 FQB5N20L	 FQB5N30TM	 FQB5N30TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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